

LM111 LM211 - LM311

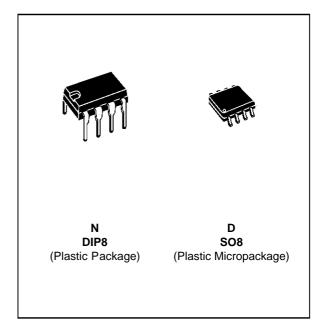
VOLTAGE COMPARATORS

MAXIMUM INPUT CURRENT : 150nA
 MAXIMUM OFFSET CURRENT : 20nA

■ DIFFERENTIAL INPUT VOLTAGE RANGE : ±30V

■ POWER CONSUMPTION: 135mW AT±15V

■ SUPPLY VOLTAGE: +5V TO ±15V ■ OUTPUT CURRENT: 50mA



DESCRIPTION

The LM111, LM211 and LM311 are voltage comparators that have low input currents.

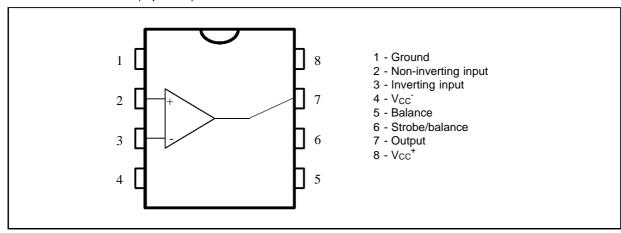
They are also designed to operate over a wide range of supply voltages: from standard ± 15 V operational amplifier supplies down to the single +5V supply used for IC logic.

Their output is compatible with RTL-DTL and TTL as well as MOS circuits and can switch voltages up to +50V at output currents as high as 50mA.

ORDER CODES

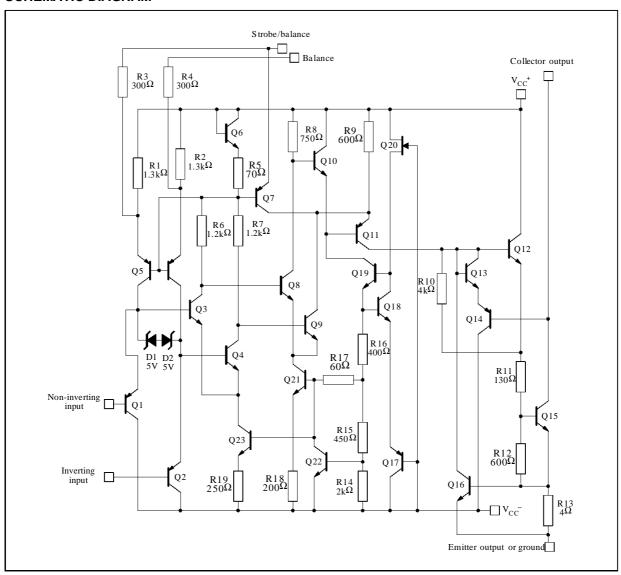
Part Number	Temperature	Package				
Fait Number	Range	N	D			
LM111	−55, 125°C	•	•			
LM211	–40, 105°C	•	•			
LM311	0, 70°C	•	•			
Example: LM311D						

PIN CONNECTIONS (top view)



October 1997 1/9

SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	LM111	LM211	LM311	Unit
Vcc	Supply Voltage	36	36	36	V
V_{id}	Differential Input Voltage	±30	±30	±30	V
V_i	Input Voltage – (note 1)	±15	±15	±15	V
P _{tot}	Power Dissipation	500			mW
T _{oper}	Operating Free-air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C
T _{stg}	Storage Temperature Range	-65 to +150	-65 to +150	-65 to +150	°C
V ₍₁₋₄₎	Ground to Negative Supply Voltage	30	30	30	V
V ₍₇₋₄₎	Output to Negative Supply Voltage	50	50	40	V

Output short-circuit duration: 10s Voltage at strobe pin: V_{CC}⁺-5V

Maximum junction temperature

LM111 : +150°C LM211 : +150°C LM311 : +150°C

Note: 1. This rating applies for ±15V supplies. The positive input voltage limit is 30V above the negative. The negative input voltage limit is equal to the negative supply voltage or 30V below the positive supply, whichever is less.



ELECTRICAL CHARACTERISTICS

 $V_{CC} = \pm 15V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

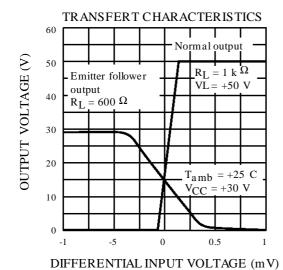
Symbol	Parameter		LM111 - LM211			LM311			Unit
Symbol	ratameter			Тур.	Max.	Min.	Тур.	Max.	Unit
V _{io}	Input Offset Voltage $(R_S \le 50k\Omega)$ – (note 1) $T_{amb} = +25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max}$.			0.7	3 4		2	7.5 10	mV
l _{io}	Input Offset Current – (note 1) $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max}.$			4	10 20		6	50 70	nA
l _{ib}	Input Bias Current – (note 1) $ T_{amb} = +25^{\circ}C $ $ T_{min.} \leq T_{amb} \leq T_{max}. $			60	100 150		100	250 300	nA
A_{vd}	Large Signal Voltage Gain		40	200		40	200		V/mV
I _{CC} ⁺	Supply Currents Positive Negative			5.1 4.1	6 5		5.1 4.1	7.5 5	mA
V _{icm}	$\begin{array}{c} \text{Input Common Mode Voltage Range} \\ T_{\text{min.}} \leq T_{\text{amb}} \leq T_{\text{max}}. \end{array}$			+13.8 -14.7	+13	-14.5	+13.8 -14.7	+13	V
Vol	Low Level Output Voltage $T_{amb} = +25^{\circ}C$, $I_{O} = 50 \text{mA}$ $T_{min,} \leq T_{amb} \leq T_{max}.$ $V_{CC} \geq +4.5 \text{ V, } V_{CC} = 0$	$V_i \le -10mV$		0.75	1.5		0.75	1.5	V
	$I_0 = 8mA$	$\begin{array}{l} V_i \leq \text{-6mV} \\ V_i \leq \text{-10mV} \end{array}$		0.23	0.4		0.23	0.4	
Іон	High Level Output Current $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max}.$	$V_i \ge + 5mV, V_O = +35V$ $V_i \ge +10mV, V_O = +5V$ $V_i \ge +5mV, V_O = +35V$		0.2	10 0.5		0.2	50	nA nA μA
I _{strobe}	Strobe Current	V = 1 0111V, V() = +00 V		3	0.0		3		mΑ
t _{re}	Response Time – (note 2)			200			200		ns

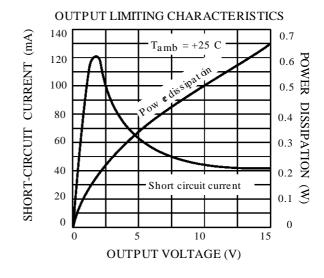
Notes: 1. The offset voltage, offset current and bias current specifications apply for any supply voltage from a single +5V supply up to ±15V

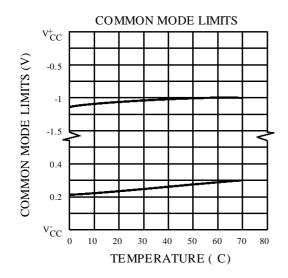
supplies.

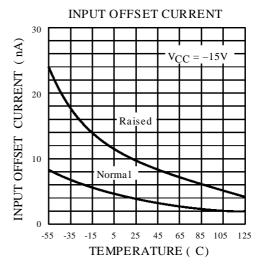
The offset voltages and offset currents given are the maximum values required to drive the output down to +1V or up to +14V with a 1mA load current. Thus, these parameters define an error band and take into account the worst-case of voltage gain and input

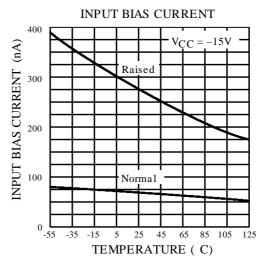
^{2.} The response time specified (see definitions) is for a 100mV input step with 5mV overdrive.

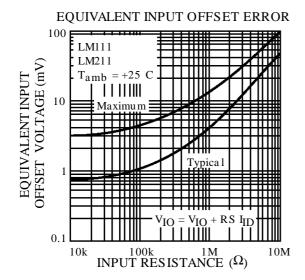


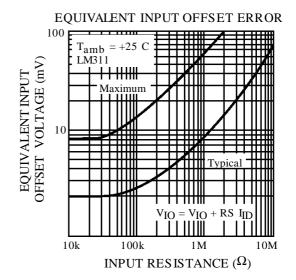




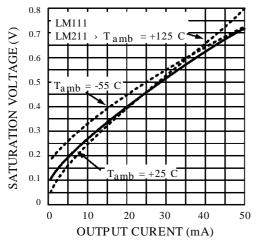


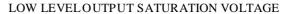


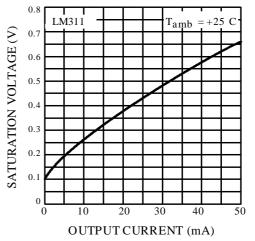


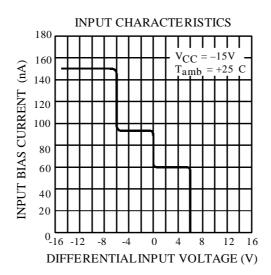


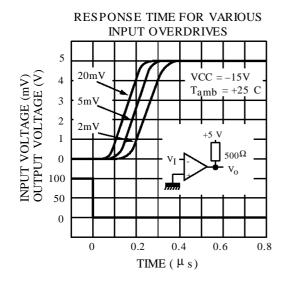
LOW LEVEL OUTPUT SATURATION VOLTAGE

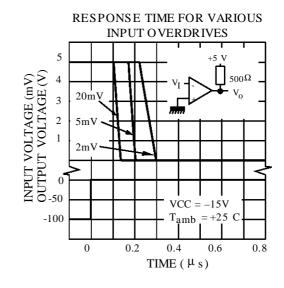


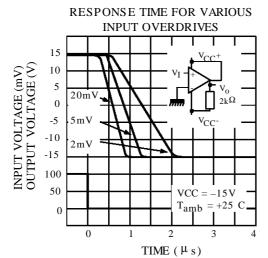


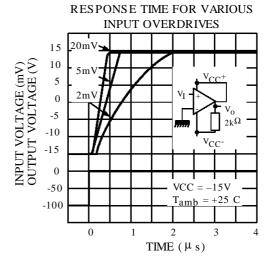






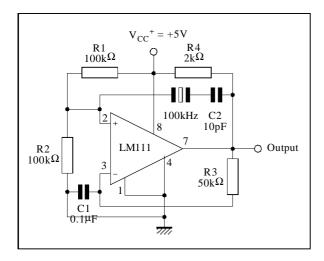




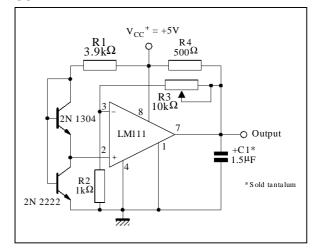


TYPICAL APPLICATIONS

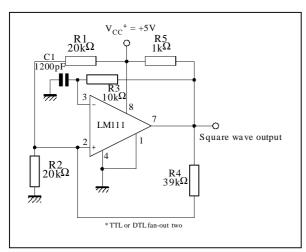
CRYSTAL OSCILLATOR



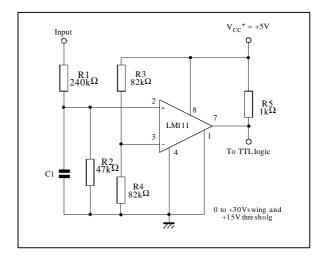
LOW VOLTAGE ADJUSTABLE REFERENCE SUPPLY



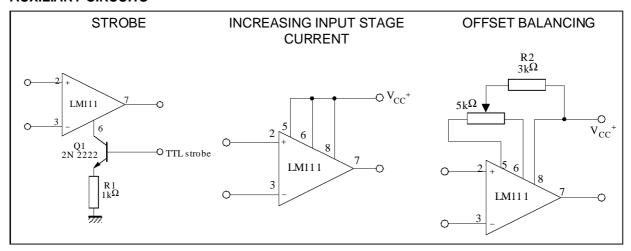
100KHz FREE RUNNING MULTIVIBRATOR



TTL INTERFACE WITH HIGH LEVEL LOGIC

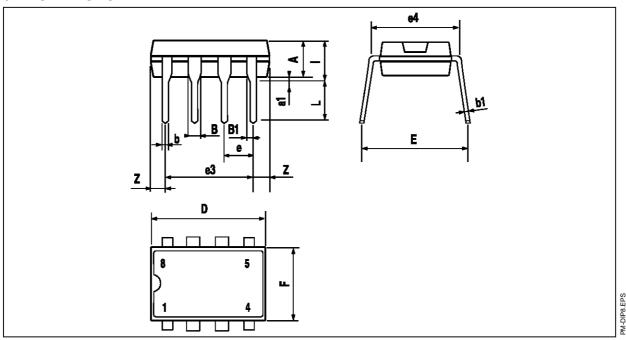


AUXILIARY CIRCUITS



PACKAGE MECANICAL DATA

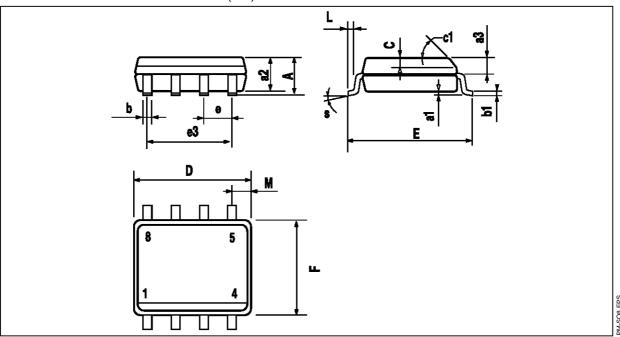
8 PINS - PLASTIC DIP



Dim.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	٦
Α		3.32			0.131		
a1	0.51			0.020			
В	1.15		1.65	0.045		0.065	
b	0.356		0.55	0.014		0.022	
b1	0.204		0.304	0.008		0.012	\neg
D			10.92			0.430	
Е	7.95		9.75	0.313		0.384	
е		2.54			0.100		П
e3		7.62			0.300		\neg
e4		7.62			0.300		
F			6.6			0260	\neg
i			5.08			0.200	
L	3.18		3.81	0.125		0.150	
Z			1.52			0.060	\neg

PACKAGE MECANICAL DATA

8 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А			1.75			0.069		
a1	0.1		0.25	0.004		0.010		
a2			1.65			0.065		
a3	0.65		0.85	0.026		0.033	7	
b	0.35		0.48	0.014		0.019		
b1	0.19		0.25	0.007		0.010		
С	0.25		0.5	0.010		0.020		
c1	45° (typ.)							
D	4.8		5.0	0.189		0.197		
E	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		3.81			0.150			
F	3.8		4.0	0.150		0.157		
L	0.4		1.27	0.016		0.050		
M			0.6			0.024		
S	8° (max.)						- 808 IRF	

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